





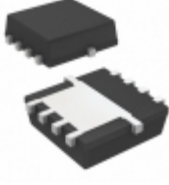

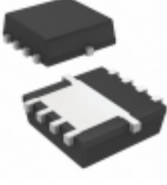


	<h2>SI7629DN-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7629DN-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 35A 1212-8 PPAK</p> <p>Datenblätter:  SI7629DN-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8555 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7629DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 35A 1212-8 PPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8555 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8
Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	3.7W (Ta), 52W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	35A (Tc)
Rds On (Max) @ Id, Vgs	4.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	177nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5790pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)































SI7629DN-T1-GE3 ist neu im Original, Suche SI7629DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7629DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7629DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI7634B VISHAY VISHAY QFN8	 SI7629DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 35A 1212-8 PPAK	 SI7634BDP VISHAY SI7634BDP VISHAY	 SI7625DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 35A 1212-8 PPAK
 SI7633DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 60A PPAK 8SO	 SI7623DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 35A 1212-8	 SI7629DN-T1 VISHAY SI7629DN-T1 VISHAY	 SI7633DP-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 60A PPAK 8SO

heiße Teile

Mehr

 SI7540DP-T1-E3	 SI7540DP-T1-GE3	 SI7540DP-T1-GE3	 SI7606DN-T1-E3	 SI7606DN-T1-GE3
 SI7611DN-T1-GE3	 SI7611DN-T1-GE3	 SI7613DN-T1-GE3	 SI7613DN-T1-GE3	 SI7615ADN-T1-GE3
 SI7615ADN-T1-GE3	 SI7615DN	 SI7615DN-T1-E3	 SI7615DN-T1-GE3	 SI7615DN-T1-GE3
 SI7617DN-T1-GE3	 SI7617DN-T1-GE3	 SI7619DN-T1-GE3	 SI7619DN-T1-GE3	 SI7621DN-T1-GE3
 SI7621DN-T1-GE3	 SI7625DN-T1-GE3	 SI7625DN-T1-GE3	 SI7629DN-T1	 SI7629DN-T1-GE3
 SI7633DP-T1-GE3	 SI7633DP-T1-GE3	 SI7634BDP	 SI7634BDP-T1-E3	 SI7634BDP-T1-E3
 SI7634BDP-T1-GE3	 SI7634BDP-T1-GE3	 SI7634DP-T1-E3	 SI7634DP-T1-GE3	 SI7635DP
 SI7635DP-T1-GE3	 SI7635DP-T1-GE3	 SI7636DP	 SI7636DP-T1-E3	 SI7636DP-T1-E3
 SI7636DP-T1-GE3	 SI7636DP-T1-GE3	 SI7637DP-T1-E3	 SI7652DP-T1-E3	 SI7652DP-T1-GE3
 SI7655DN-T1-GE3	 SI7655DN-T1-GE3	 SI7658ADP	 SI7658ADP-T1-E3	 SI7658ADP-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited